



DMJ70H601SK3

700V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) Max	I _D T _C = +25°C
700V	0.6Ω @ V _{GS} = 10V	8A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Adaptors
- LCD & PDP TVs
- Lightings

Features

- Low Gate Input Resistance
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

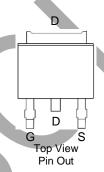
Mechanical Data

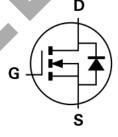
- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.33 grams (Approximate)





Top View





Internal Schematic

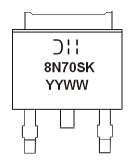
Ordering Information (Note 4)

Part Number	Pankago	Packing		
Fait Number	Package	Qty.	Carrier	
DMJ70H601SK3-13	TO252 (DPAK) (Type TH)	2,500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



| | = Manufacturer's Marking
 8N70SK = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 22 = 2022)
 WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	700	V	
Gate-Source Voltage		Vgss	±30	V
Continuous Drain Current (Note 5) V _{GS} = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	lσ	8 6.4	А
Maximum Body Diode Forward Current (Note 6)		Is	4	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	15	Α
Avalanche Current (Note 7)	L = 60mH	las	1.7	Α
Avalanche Energy (Note 7)	L = 60mH	Eas	86	mJ
Peak Diode Recovery dv/dt (Note 7)		dv/dt	7	V/ns

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	<u> </u>	Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_C = +25^{\circ}C$	D-	125	W
Total Fower Dissipation (Note 3)	Tc = +100°C	PD	50	
Thermal Resistance, Junction to Ambient (Note 6)		Reja	72	°C/W
Thermal Resistance, Junction to Case (Note 5)		Rejc	1.0	C/VV
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

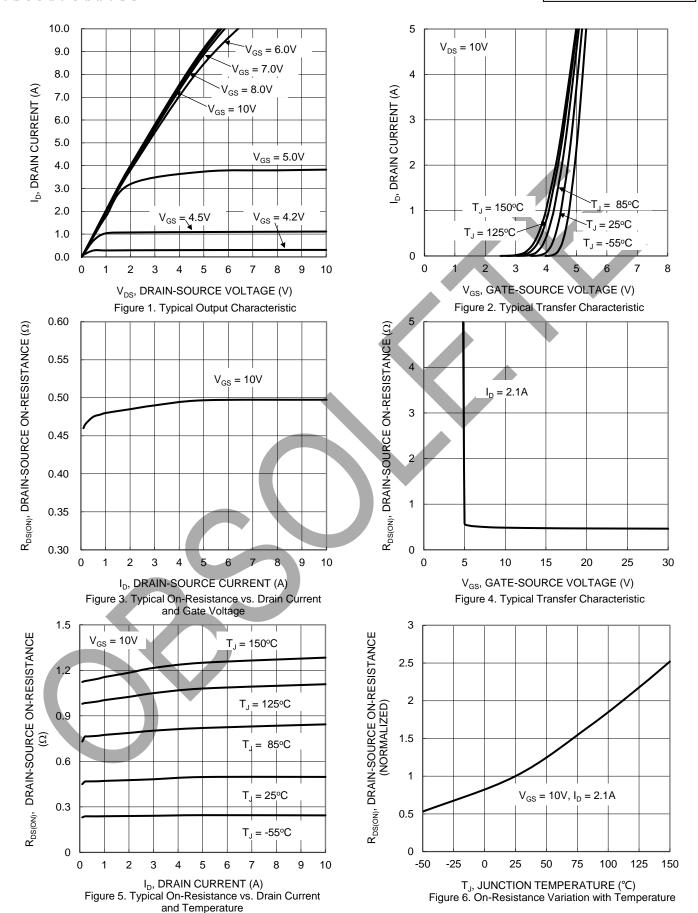
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Turn	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Syllibol	WIII	Тур	IVIAX	Ollit	rest Condition	
, ,	DV	700			V	N 01/1 050::A	
Drain-Source Breakdown Voltage	BVDSS					V _G S = 0V, I _D = 250μA	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μΑ	V _{DS} = 700V, V _{GS} = 0V	
Gate-Source Leakage	Igss		_	100	nA	$V_{GS} = \pm 30V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS} (TH)	2	3.4	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	0.5	0.6	Ω	Vgs = 10V, ID = 2.1A	
Diode Forward Voltage	VsD	_	0.85	1.3	V	Vgs = 0V, Is = 2.1A	
DYNAMIC CHARACTERISTICS (Note 7)				•			
Input Capacitance	Ciss	_	686	_		V 50V (4MI)	
Output Capacitance	Coss	_	267	_	pF	V _{DS} = 50V, f = 1MHz, V _{GS} = 0V	
Reverse Transfer Capacitance	Crss	_	8	_		VGS ≡ UV	
Gate Resistance	Rg	_	2.6	_	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz	
Total Gate Charge	Qg	_	20.9	_		V _{DD} = 560V, I _D = 8A, V _{GS} = 10V	
Gate-Source Charge	Qgs	_	3.0	_	nC		
Gate-Drain Charge	Qgd	_	9.4	_		VGS = 10V	
Turn-On Delay Time	t _{D(ON)}	_	10	_			
Turn-On Rise Time	t _R	_	23	_	no	V _{DD} = 350V, V _{GS} = 10V,	
Turn-Off Delay Time	tD(OFF)	_	32	_	ns	$R_G = 4.7\Omega$, $I_D = 8A$	
Turn-Off Fall Time	tF	_	17	_			
Body Diode Reverse Recovery Time	trr		261	_	ns		
Body Diode Reverse Recovery Time (T _J = +150°C)	trr		337	_	ns	1- 00 41/44 4000///-	
Body Diode Reverse Recovery Charge	Q _{RR}	_	3.0	_	μC	$Is = 8A$, $dI/dt = 100A/\mu s$	
Body Diode Reverse Recovery Charge (T _J = +150°C)	Q _{RR}		4.0	_	μC]	

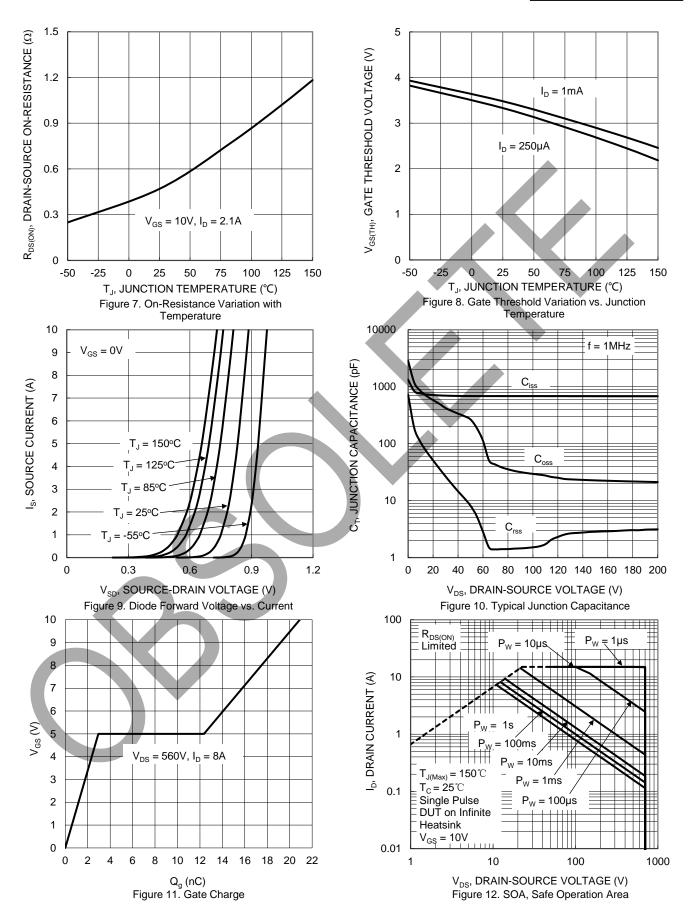
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.
 Device mounted on FR-4 substrate PC board, 2oz. copper, with minimum recommended pad layout.
 Guaranteed by design. Not subject to production testing. Notes:

8. Short duration pulse test used to minimize self-heating effect.











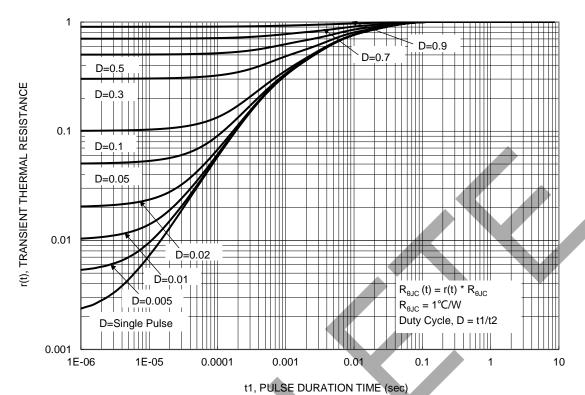


Figure 13. Transient Thermal Resistance

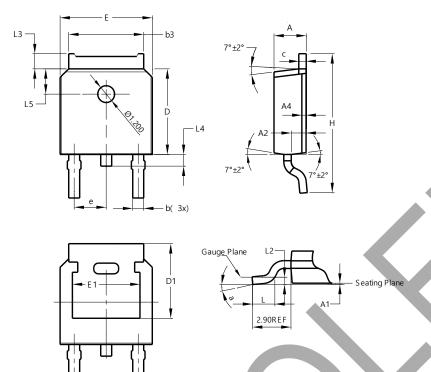
DMJ70H601SK3 Document number: DS39420 Rev. 5 - 4



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK) (Type TH)

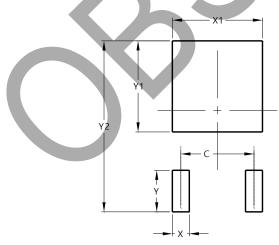


TO252 (DPAK)					
(Type TH)					
Dim	Min	Max	Тур		
Α	2.20	2.38	2.30		
A1	0.00	0.10	-		
A2	0.97	1.17	1.07		
A4	0.10 REF				
q	0.72	0.85	0.78		
b3	5.23	5.45	5.33		
C	0.47	0.58	0.53		
О	6.00	6.20	6.10		
D1	5.30 REF				
е	2.286 BSC				
È	6.50	6.70	6.60		
E1	4.70	4.92	4.83		
H	9.90	10.30	10.10		
٦	1.40	1.70	1.60		
L2	0.51 BSC				
L3	0.90	1.25	-		
L4	0.60	1.00	0.80		
L5	1.70	1.90	1.80		
а	0°	8°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK) (Type TH)



Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Υ	2.600			
Y1	5.700			
Y2	10 700			



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